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ON THE PRESSURE DEPENDENCE OF SUPERCONDUCTIVITY IN TRANSITION METAL DICHALCOGENIDE LAYER CRYSTALS

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Résumé. — Les données expérimentales actuelles dans ce domaine suggèrent que les fortes températures critiques sont dues à de fortes densités électroniques au niveau de Fermi plutôt qu'à des modes de phonons mous.

Abstract. — Present evidence in this field suggests that high critical temperatures are due to large electronic densities at the Fermi level rather than to soft phonon modes.

Recent measurements of the pressure dependence of superconductivity in transition metal dichalcogenide layer crystals have shown different behaviour in sulfur and selenium compounds [1].

In both 2H Nb S_2 and 3R Nb S_2 , the critical temperature T_c and the critical field H_{c2} , show very little variation with pressure, at least up to 10 kbar (Fig. 1a, b).

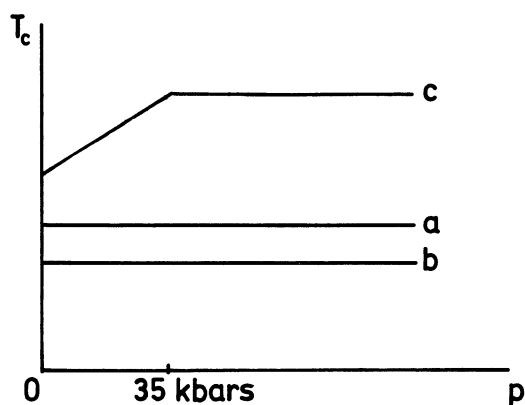


FIG. 1. — Pressure dependence of the critical temperature T_c in transition metal dichalcogenide layer compounds (schematic) : a) 2H Nb S_2 ; b) 3R Nb S_2 ; c) 2H Nb Se_2 .

In 2H Nb Se_2 , the critical temperature T_c increases rapidly with pressure up to 35 kbar, then shows little variation with pressure up to 140 kbar (Fig. 1c). H_{c2} increases with pressure in the low pressure range (measured up to 13 kbar), when measured both parallel and perpendicular to the layers.

The high value and pressure variation of T_c in the Se compound have been related to the fact that it exhibits a low temperature phase transformation which is clearly due to a *Peierls instability*, i.e. on cooling

down, the electron-phonon couplings stabilizes a new phase which opens gaps at the Brillouin zone boundary near to the Fermi surface of the high temperature phase [2].

We want to suggest here that the superlattice phase disappears above 35 kbar, leaving the undistorted phase, as observed in the sulfur compound. This is strongly suggested by the constancy of T_c above 35 kbars. It would of course be of interest to check this directly or by a study of transport properties.

If this suggestion is right, it should allow the contribution of soft phonon modes and a high electronic density at the Fermi level to the high T_c 's to be distinguished.

1) The existence of a large and pressure independent T_c in the Se compound over a very large range of pressures where the superlattice phase would be unstable would rule out the soft phonon modes associated with such a phase as responsible for high T_c 's. Indeed it is difficult to believe that any phonon mode could remain in the soft critical state over such a large range of pressures. It looks therefore extremely probable that the high T_c observed in the Se phase above 35 kbar is to be related to a large density of electronic states at the Fermi level $N(E_F)$. Indeed one expects a narrower d band, thus a larger value of $N(E_F)$ in the Se compound than in the S ones, because the larger atomic radii of Se compared with S induce the Nb atoms to be further apart, both within metallic planes and between metallic planes.

2) The creation of the superlattice phase lowers T_c . This is difficult to understand on a soft phonon mode picture, where a minimum of T_c should be expected when the superlattice phase just disappears under pressure, thus tentatively at 35 kbars. It is again very

easy to understand if T_c is related more to $N(E_F)$: one knows that the superlattice phases become stable because, by opening gaps at Brillouin zone boundaries near to Fermi surfaces, they lower the average electronic energy in increasing $N(E)$ below E_F at the expense of $N(E_F)$ (Fig. 2).

The effect of pressure in the Se compound is thus likely to be initially to increase $N(E_F)$ by reducing the gaps at some Brillouin zone boundaries, owing to a reduction in strength of the superstructure due to *Peierls instability*.

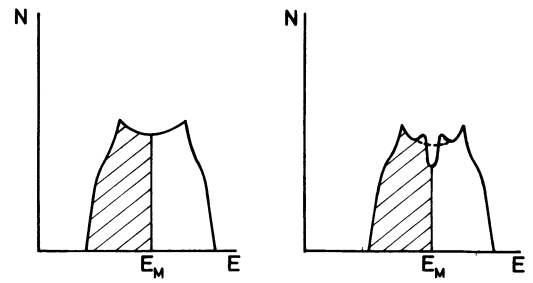


FIG. 2. — Density of states of the d band (schematic) : a) normal undistorted phase ; b) superlattice phase.

References

- [1] MOLINIÉ, P., JÉROME, D. and GRANT, A. J., *Phil. Mag.* **30** (1974) 1091. [2] WILSON, J. A., DI SALVO, F. J. and MAHAJAN, S., *Adv. Phys.* **24** (1975) 117.